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L Number	Hits	Search Text	DB	Time stamp
13	44	nanostructure and (cable)	USPAT;	2003/03/02 14:41
			US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM_TDB	
18	22	nanocomposite and semiconducting	USPAT;	2003/03/02 15:34
			US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
19	0	(nanocomposite and semiconducting) and	USPAT;	2003/03/02 15:34
		cable	US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM TDB	
20	58	(nanocomposite or nanostructure or	USPAT;	2003/03/02 15:35
20		(nanocomposite near material)) and cable	US-PGPUB;	
		-	EPO; JPO;	
			DERWENT;	
_	1011	(174/36).CCLS.	IBM_TDB USPAT;	2003/02/28 13:49
	1011	(1/4/30).CCLS.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	. 24	(high adi fraggers) noon (IBM_TDB USPAT;	2003/02/28 10:29
-	24	(high adj frequency) near (power adj	USPAT; US-PGPUB;	2003/02/28 10:29
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	730	(high adj frequency) near cable	USPAT;	2003/02/28 10:31
			US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	0	"plurality of insulated conductors"	USPAT;	2003/02/28 13:59
			US-PGPUB; EPO; JPO;	
			DERWENT;	
1			IBM_TDB	
-	8	vinyl near conductors	USPĀT;	2003/02/28 14:01
			US-PGPUB;	2
			EPO; JPO; DERWENT;	
			IBM TDB	
-	44	vinyl and (multiconductor adj cable)	USPĀT;	2003/02/28 14:08
			US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
-	11393	vinyl and cable	USPĀT;	2003/02/28 14:06
	•		US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM TDB	
_	1691	(hollow or (empty adj center))and (vinyl	USPAT;	2003/02/28 14:07
		and cable)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
_	46	(counter adj (electromagnetic adj force))	IBM_TDB USPAT;	2003/02/28 14:10
		(11230120mag.10010 day 10100//	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
I _	2	(alastromagnetic adi force) and (/hella-	IBM_TDB	2002/02/20 14.10
-	2	(electromagnetic adj force) and ((hollow or (empty adj center))and (vinyl and	USPAT; US-PGPUB;	2003/02/28 14:10
		cable))	EPO; JPO;	
			DERWENT;	
L			IBM_TDB	

	5	(electromagnetic adj force) and (vinyl and	USPAT;	2003/02/28 14:15
_	5	cable)	US-PGPUB;	2003/02/28 14.13
		cable)	EPO; JPO;	
		,	DERWENT;	
			IBM TDB	
	1.4		USPAT;	2003/02/28 17:26
-	14	nanocomposite and cable	1	2003/02/28 17:26
			US-PGPUB;	
			EPO; JPO; DERWENT;	
	م م	nanocomposite and semiconducting	IBM_TDB USPAT;	2003/03/02 15:34
-	22	nanocomposite and semiconducting	US-PGPUB;	2003/03/02 13:34
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:			EPO; JPO;	
			DERWENT;	
	1.0		IBM_TDB	0003/00/00 17:33
-	18	nano and semiconducting and cable	USPAT;	2003/02/28 17:33
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	0000/00/00 17 00
-	19	nano and (power adj cable)	USPĀT;	2003/02/28 17:39
			US-PGPUB;	
			EPO; JPO;	·
	ļ		DERWENT;	
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-	0	, , , , , , , , , , , , , , , , , , ,	USPAT;	2003/02/28 18:04
		semiconducting and cable	US-PGPUB;	
ŀ	1		EPO; JPO;	
Ì			DERWENT;	ļ
			IBM_TDB	, ,
_	4	(inorganic adj compound) and	USPAT;	2003/02/28 19:22
ļ		semiconducting and cable	US-PGPUB;	
1			EPO; JPO;	
}			DERWENT;	
		[IBM_TDB	
- .	39	(11	USPAT;	2003/02/28 19:25
	<u> </u>	cable)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
1	_	, , , , , , , , , , , , , , , , , , , ,	IBM_TDB	0000 (00 (00 00 00 00
-	2	nanostructure and ((semiconducting adj	USPAT;	2003/02/28 19:28
		layers) and (power adj cable))	US-PGPUB;	
1			EPO; JPO;	
			DERWENT;	
		, ,	IBM_TDB	
-	14	nanostructure and (power adj cable)	USPAT;	2003/02/28 19:31
			US-PGPUB;	
i			EPO; JPO;	
			DERWENT;	
		[,	IBM_TDB	
-	30	(USPAT;	2003/02/28 19:31
		(nanostructure and (power adj cable))	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
L			IBM TDB	